

Bipolar Transistors Silicon PNP Epitaxial Type (PCT Process)(Bias Resistor built-in Transistor)

RN2114/15/16/17/18

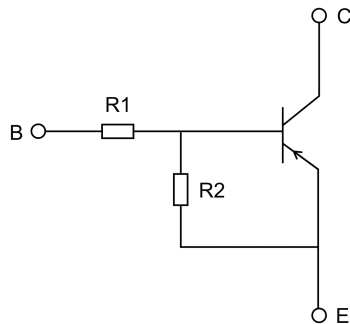
1. Applications

- Switching
- Inverter Circuits
- Interfacing
- Driver Circuits

2. Features

- (1) AEC-Q101 qualified (Please see the orderable part number list)
- (2) The integrated bias resistor reduces the number of external parts required, making it possible to reduce system size and assembly time.
- (3) Toshiba offers transistors with a wide range of resistance to accommodate various circuit designs.
- (4) Complementary to RN1114 to RN1118

3. Equivalent Circuit

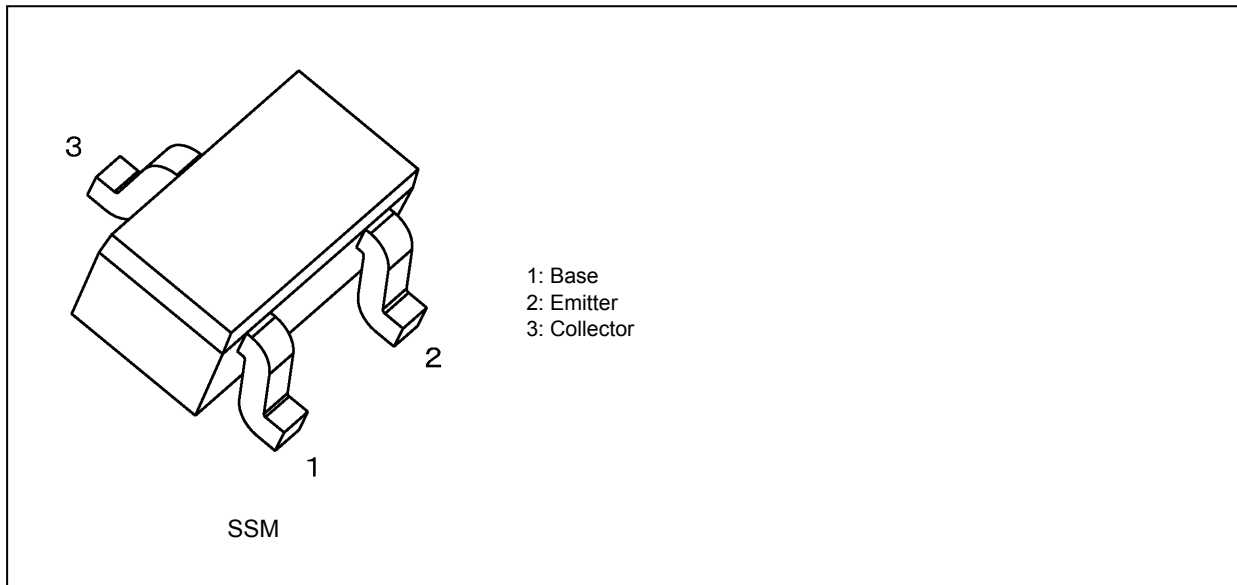


4. Bias Resistor Values

Part No.	R1 (kΩ)	R2 (kΩ)
RN2114	1	10
RN2115	2.2	10
RN2116	4.7	10
RN2117	10	4.7
RN2118	47	10

Start of commercial production
1994-08

5. Packaging and Pin Assignment



6. Orderable part number

Orderable part number		AEC-Q101	Note
RN2114	RN2114,LF	—	General Use
	RN2114,LXGF	YES (Note 1)	Unintended Use (Note 1)
RN2115	RN2115,LF	—	General Use
	RN2115,LXGF	YES (Note 1)	Unintended Use (Note 1)
	RN2115,LXHF	YES	Automotive Use
RN2116	RN2116,LF	—	General Use
	RN2116,LXGF	YES (Note 1)	Unintended Use (Note 1)
	RN2116,LXHF	YES	Automotive Use
RN2117	RN2117(TE85L,F)	—	General Use
	—	YES (Note 1)	Unintended Use (Note 1)

Note 1: For more information, please contact our sales or use the inquiry form on our website.

7. Absolute Maximum Ratings (Note) (Unless otherwise specified, $T_a = 25\text{ }^\circ\text{C}$)

Characteristics		Symbol	Rating	Unit
Collector-base voltage	RN2114 to RN2118	V_{CBO}	-50	V
Collector-emitter voltage		V_{CEO}	-50	
Emitter-base voltage	RN2114	V_{EBO}	-5	V
	RN2115		-6	
	RN2116		-7	
	RN2117		-15	
	RN2118		-25	
Collector current	RN2114 to RN2118	I_C	-100	mA
Collector power dissipation		P_C	100	mW
Junction temperature		T_j	150	$^\circ\text{C}$
Storage temperature		T_{stg}	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

8. Electrical Characteristics (Unless otherwise specified, $T_a = 25\text{ }^\circ\text{C}$)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit	
Collector cut-off current	RN2114 to RN2118	I_{CBO}	$V_{CB} = -50\text{ V}, I_E = 0\text{ mA}$	—	—	-100	nA
		I_{CEO}	$V_{CE} = -50\text{ V}, I_B = 0\text{ mA}$	—	—	-500	nA
Emitter cut-off current	RN2114	I_{EBO}	$V_{EB} = -5\text{ V}, I_C = 0\text{ mA}$	-0.35	—	-0.65	mA
	RN2115		$V_{EB} = -6\text{ V}, I_C = 0\text{ mA}$	-0.37	—	-0.71	
	RN2116		$V_{EB} = -7\text{ V}, I_C = 0\text{ mA}$	-0.36	—	-0.68	
	RN2117		$V_{EB} = -15\text{ V}, I_C = 0\text{ mA}$	-0.78	—	-1.46	
	RN2118		$V_{EB} = -25\text{ V}, I_C = 0\text{ mA}$	-0.33	—	-0.63	
DC current gain	RN2114 to RN2116	h_{FE}	$V_{CE} = -5\text{ V}, I_C = -10\text{ mA}$	50	—	—	—
	RN2117			30	—	—	—
	RN2118			50	—	—	—
Collector-emitter saturation voltage	RN2114 to RN2118	$V_{CE(sat)}$	$I_C = -5\text{ mA}, I_B = -0.25\text{ mA}$	—	-0.1	-0.3	V
Input voltage (ON)	RN2114	$V_{I(ON)}$	$V_{CE} = -0.2\text{ V}, I_C = -5\text{ mA}$	-0.5	—	-2.0	V
	RN2115			-0.6	—	-2.5	
	RN2116			-0.7	—	-2.5	
	RN2117			-1.5	—	-3.5	
	RN2118			-2.5	—	-10.0	
Input voltage (OFF)	RN2114	$V_{I(OFF)}$	$V_{CE} = -5\text{ V}, I_C = -0.1\text{ mA}$	-0.3	—	-0.9	V
	RN2115			-0.3	—	-1.0	
	RN2116			-0.3	—	-1.1	
	RN2117			-0.3	—	-3.0	
	RN2118			-0.5	—	-5.7	
Transition frequency	RN2114 to RN2118	f_T	$V_{CE} = -10\text{ V}, I_C = -5\text{ mA}$	—	200	—	MHz
Collector output capacitance	RN2114 to RN2118	C_{ob}	$V_{CB} = -10\text{ V}, I_E = 0\text{ mA}, f = 1\text{ MHz}$	—	3.0	6.0	pF
Input resistance	RN2114	R_1	-	0.7	1.0	1.3	k Ω
	RN2115			1.54	2.2	2.86	
	RN2116			3.29	4.7	6.11	
	RN2117			7.0	10.0	13.0	
	RN2118			32.9	47.0	61.1	
Resistor ratio	RN2114	R1/R2	-	—	0.1	—	—
	RN2115			—	0.22	—	
	RN2116			—	0.47	—	
	RN2117			—	2.13	—	
	RN2118			—	4.7	—	

9. Marking

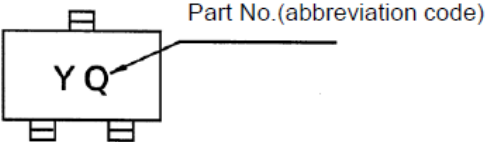


Fig. 9.1 Marking RN2114

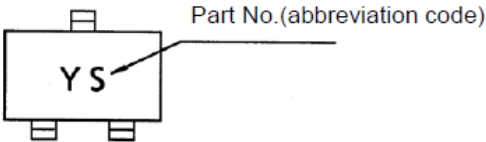


Fig. 9.2 Marking RN2115

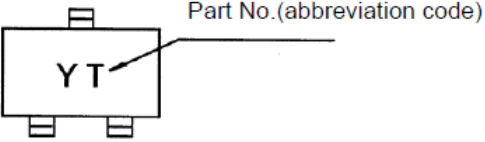


Fig. 9.3 Marking RN2116

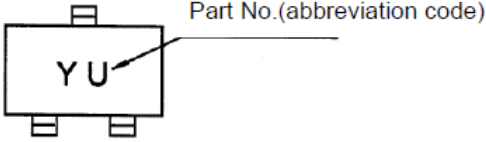


Fig. 9.4 Marking RN2117

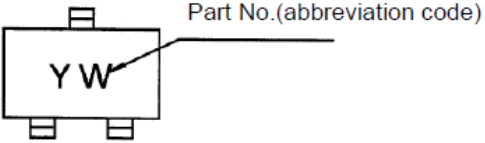


Fig. 9.5 Marking RN2118

10. Characteristics Curves (Note)

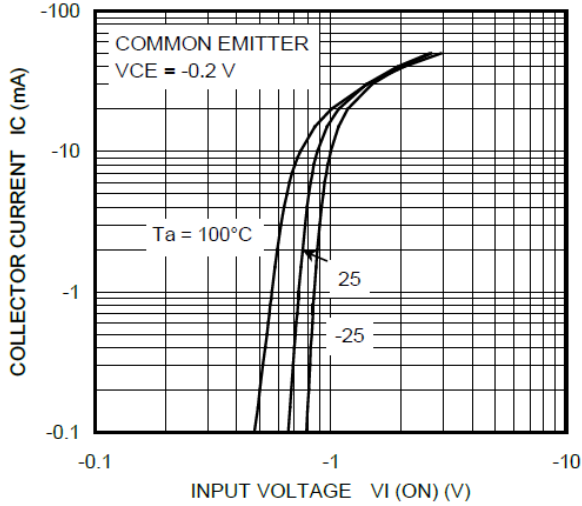


Fig. 10.1 RN2114 I_C - $V_{I(ON)}$

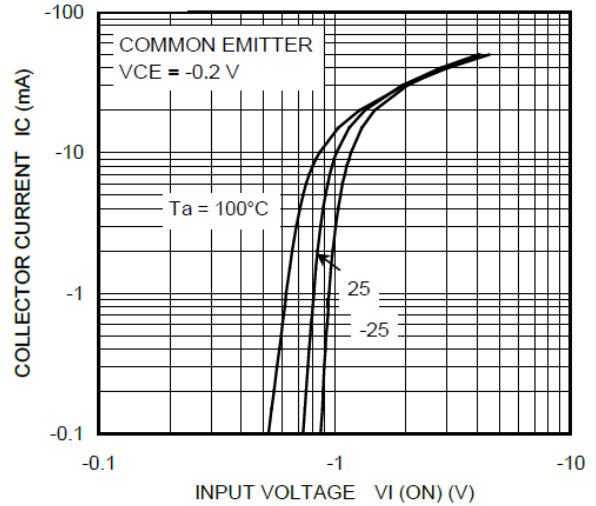


Fig. 10.2 RN2115 I_C - $V_{I(ON)}$

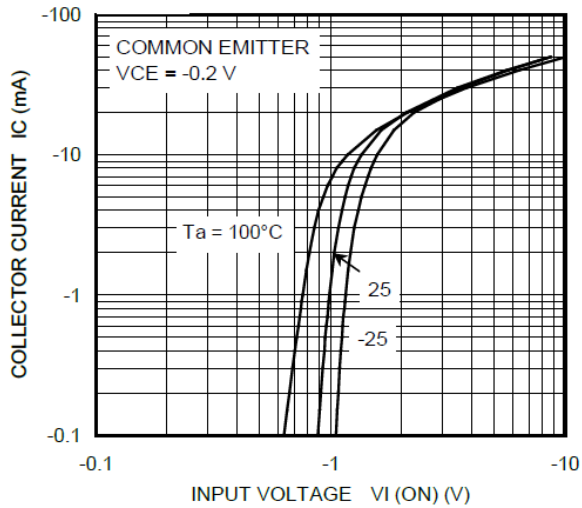


Fig. 10.3 RN2116 I_C - $V_{I(ON)}$

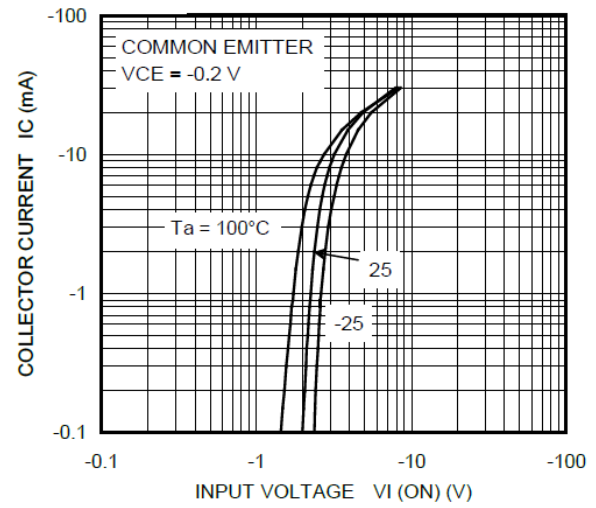


Fig. 10.4 RN2117 I_C - $V_{I(ON)}$

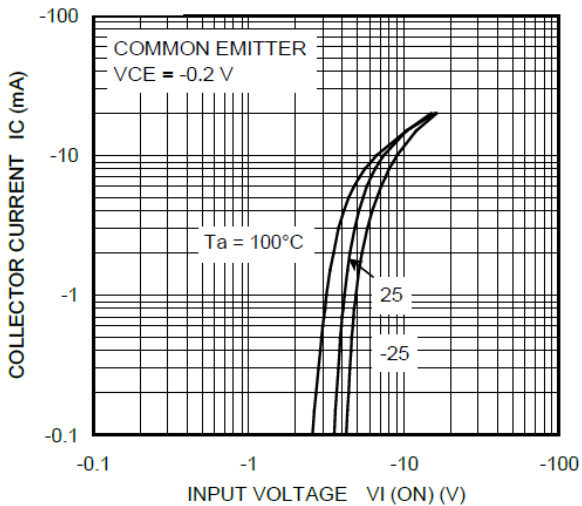


Fig. 10.5 RN2118 I_C - $V_{I(ON)}$

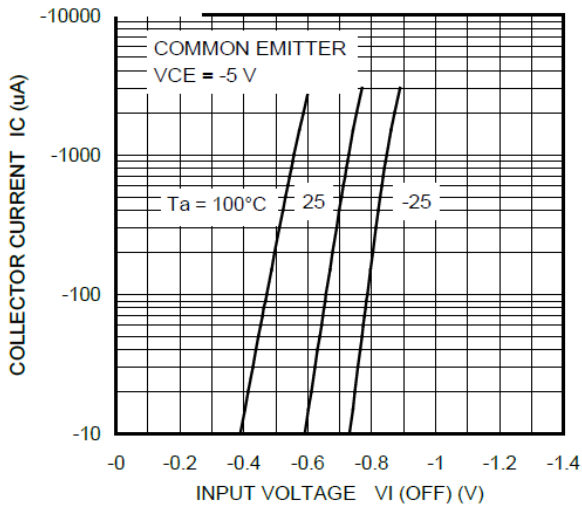


Fig. 10.6 RN2114 I_C - V_I (OFF)

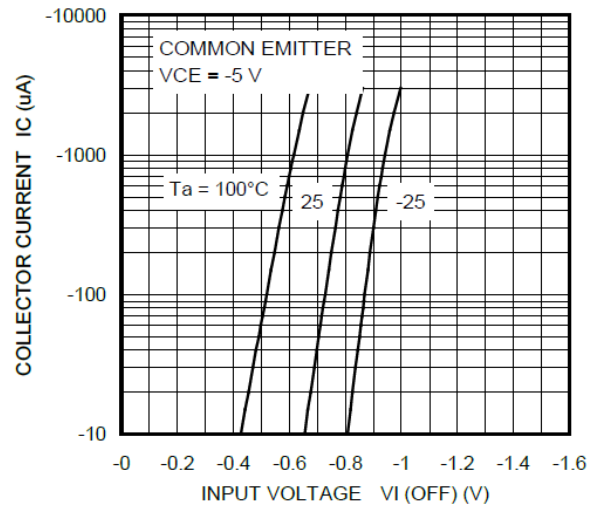


Fig. 10.7 RN2115 I_C - V_I (OFF)

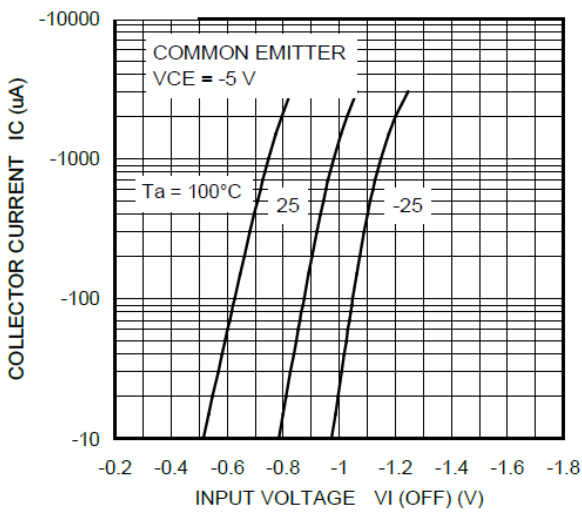


Fig. 10.8 RN2116 I_C - V_I (OFF)

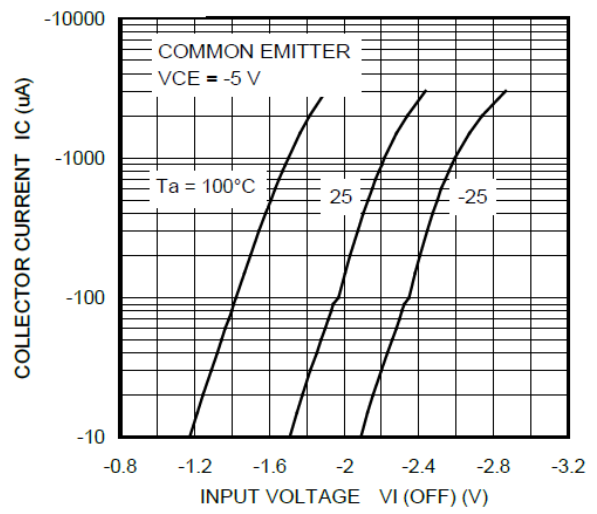


Fig. 10.9 RN2117 I_C - V_I (OFF)

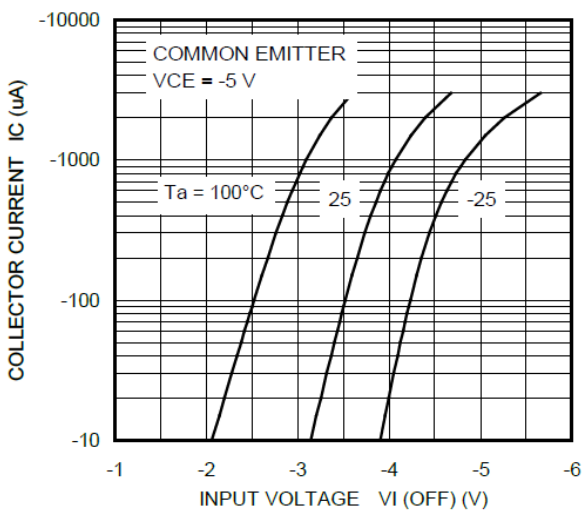


Fig. 10.10 RN2118 I_C - V_I (OFF)

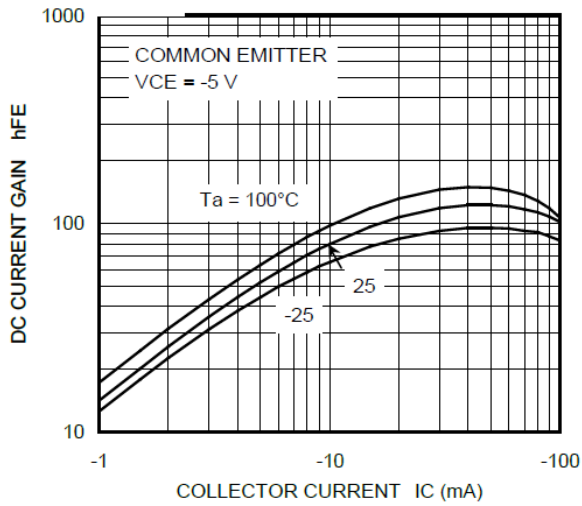


Fig. 10.11 RN2114 $h_{FE}-I_C$

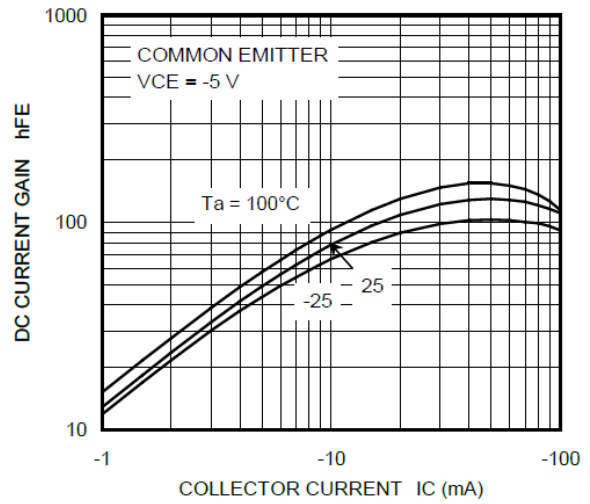


Fig. 10.12 RN2115 $h_{FE}-I_C$

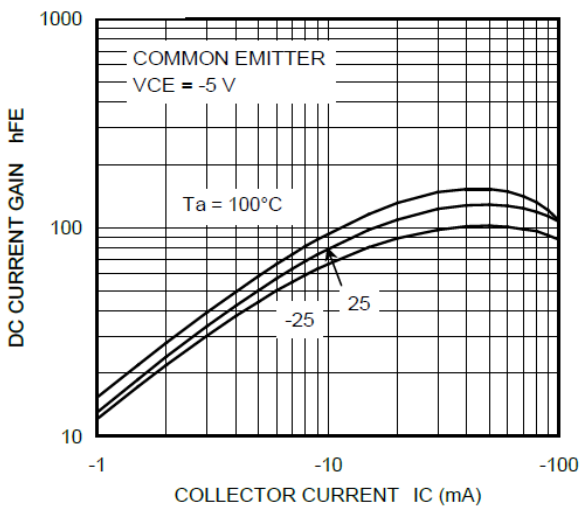


Fig. 10.13 RN2116 $h_{FE}-I_C$

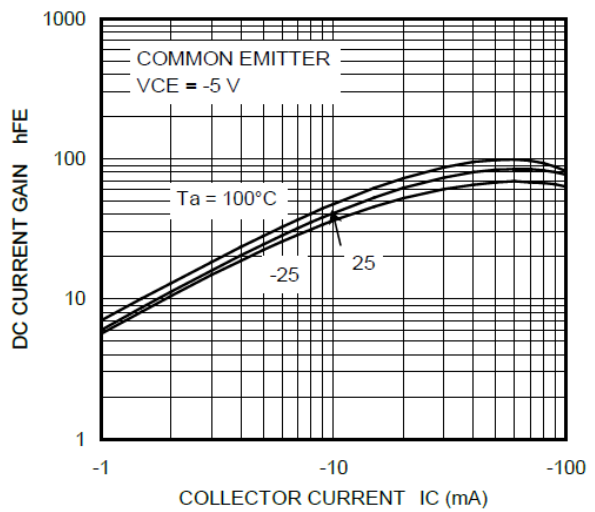


Fig. 10.14 RN2117 $h_{FE}-I_C$

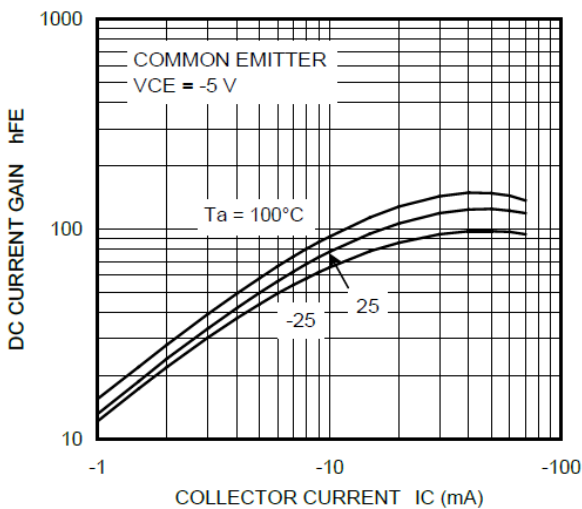


Fig. 10.15 RN2118 $h_{FE}-I_C$

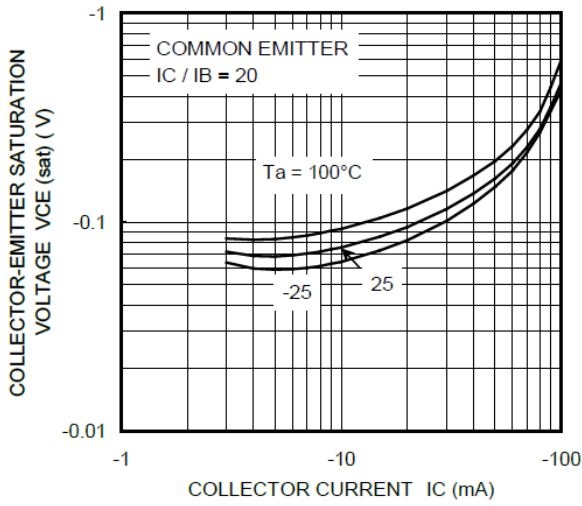


Fig. 10.16 RN2114 $V_{CE(sat)}-I_C$

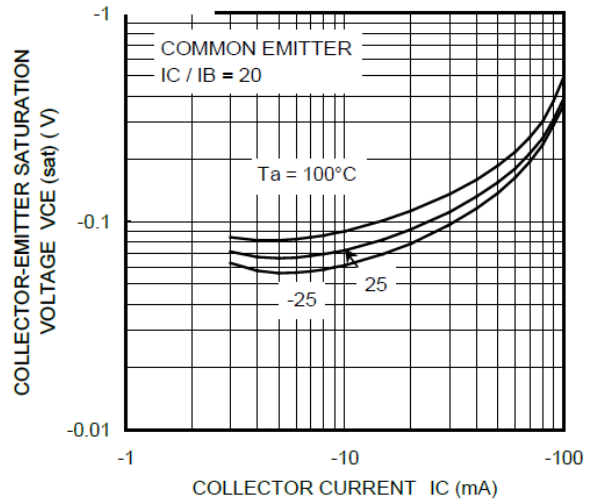


Fig. 10.17 RN2115 $V_{CE(sat)}-I_C$

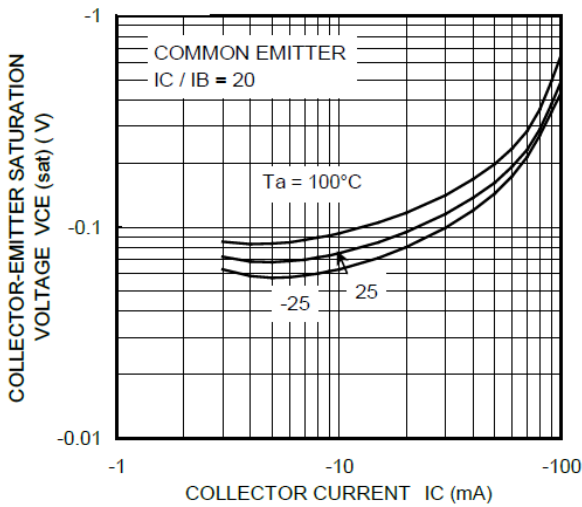


Fig. 10.18 RN2116 $V_{CE(sat)}-I_C$

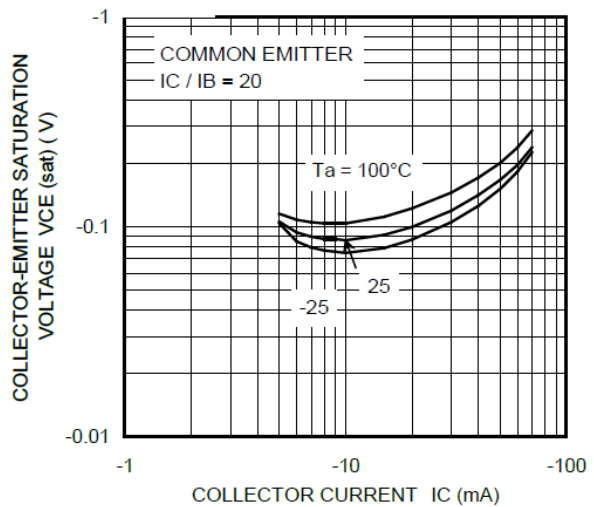


Fig. 10.19 RN2117 $V_{CE(sat)}-I_C$

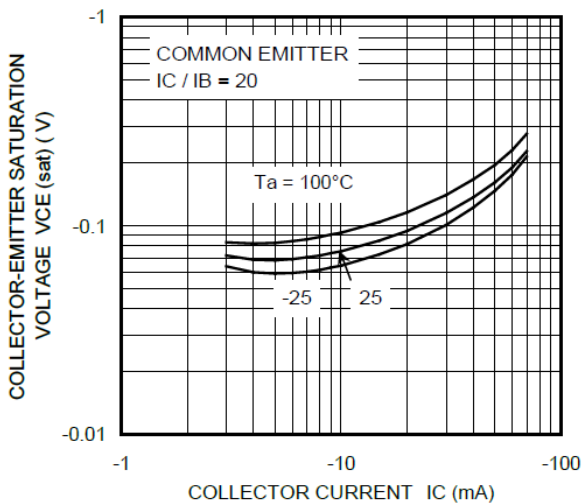
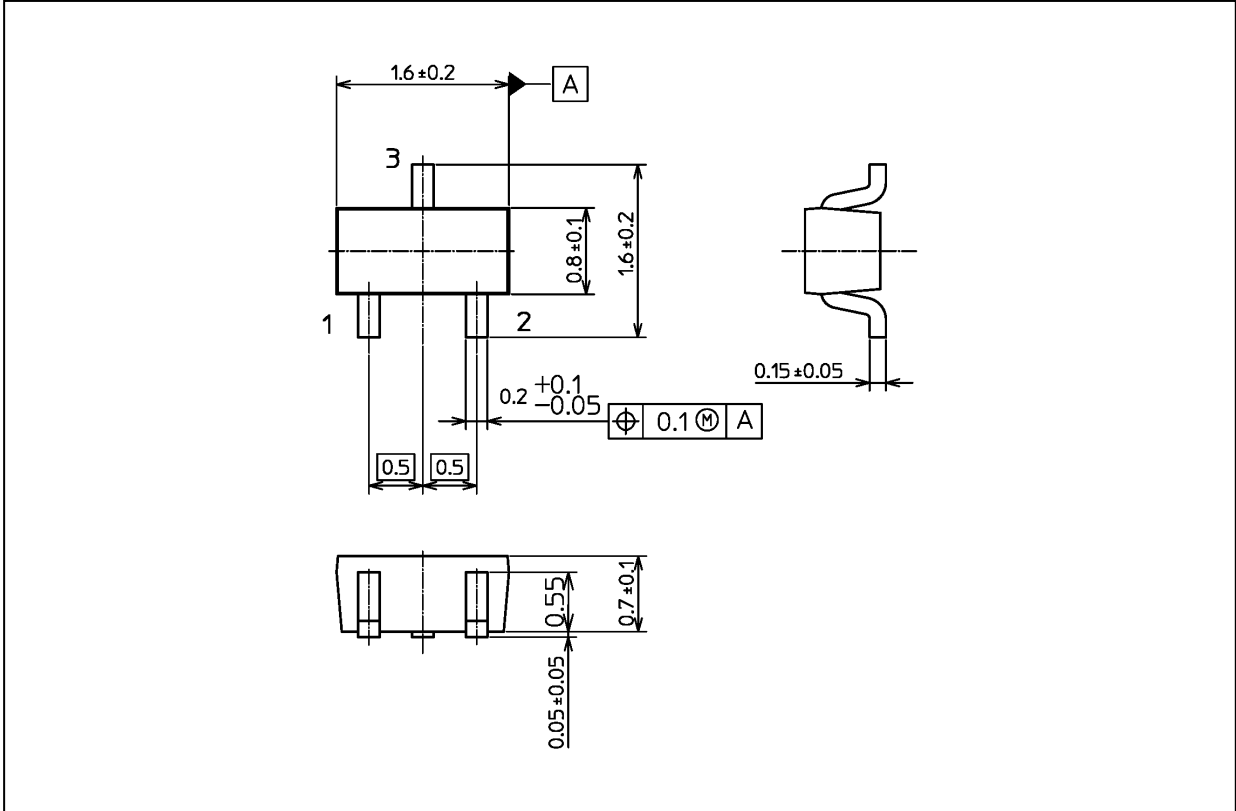


Fig. 10.20 RN2118 $V_{CE(sat)}-I_C$

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

Unit: mm



Weight: 2.4 mg (typ.)

Package Name(s)
Nickname: SSM

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